

RL201G-RL207G

Technical Data Data Sheet N0558, Rev. A **Green Products**

RL201G THRU RL207G **GLASS PASSIVATED SILICON RECTIFIER**

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes

FEATURES

- The plastic package carries Underwriters Laboratory
- Flammability Classification 94V-0
- Construction utilizes void-free
- molded plastic technique Low reverse leakage
- High forward surge current capability
 High temperature soldering guaranteed: 250°C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

MECHANICAL DATA

Case: DO-15 molded plastic body Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026 Polarity: Color band denotes cathode end Mounting Position: Any Weight: 0.014 ounce, 0.40 grams Marking: Part Name, SSG and Date Code

MARKING DIAGRAM



RL201G

= Part Name

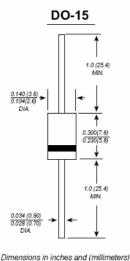
Cautions: Molding resin Epoxy resin UL:94V-0

ORDERING INFORMATION

Device	Package	Shipping			
RL201G-RL207G	DO-15 (Pb-Free)	3000pcs / tape			

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

• Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 • • FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •





RL201G-RL207G

Technical Data Data Sheet N0558, Rev. A

Green Products

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

	SYMBOLS	RL 201G	RL 202G	RL 203G	RL 204G	RL 205G	RL 206G	RL 207G	UNITS
Maximum repetitive peak reverse voltage		50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	Vrms	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current 0.375″(9.5mm) lead length at T a =75℃	l _(AV)	2.0						Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	70.0						Amps	
Maximum instantaneous forward voltage at 2.0A	Vf	1.1						Volts	
Maximum DC reverse current Ta=25℃ at rated DC blocking voltage Ta=100℃	lr	lR 5.0 50.0			μA				
Typical junction capacitance (NOTE 1)	CJ	20.0						рF	
Typical thermal resistance (NOTE 2)	R _e ja	50.0						°C/W	
Operating junction and storage temperature range	Tj,Tstg	-65 to +175						°C	

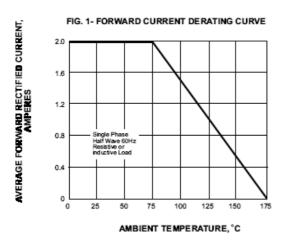
Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Technical Data Green Products Data Sheet N0558, Rev. A RATINGS AND CHARACTERISTIC CURVES RL201G THRU RL207G



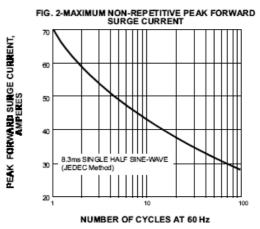
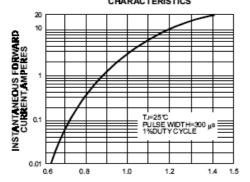


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLEAGE, VOLTS

FIG. 5-TYPICAL JUNCTION CAPACITANCE

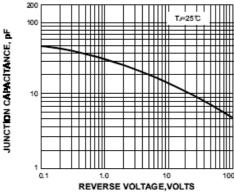
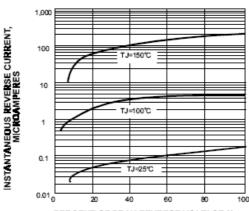
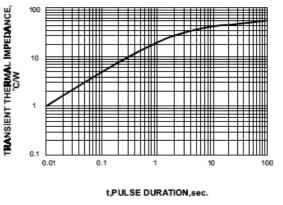


FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE,%

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 [86) 25-87123907
FAX (86) 25-87123900
World Wide Web Site - http://www.sangdest.com.cn
E-Mail Address - sales@ sangdest.com.cn



RL201G-RL207G

Technical Data Data Sheet N0558, Rev. A

Green Products

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.